









	<h2>FQU5P20TU</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQU5P20TU
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET P-CH 200V 3.7A IPAK
	Datenblätter:  FQU5P20TU.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1310 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQU5P20TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 200V 3.7A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1310 pcs Stock
detaillierte Beschreibung	P-Channel 200V 3.7A (Tc) 2.5W (Ta), 45W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-PAK
Verlustleistung (max)	2.5W (Ta), 45W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.7A (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 1.85A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	430pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































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Sie können auch interessiert sein:

 <p>FQU5P20TU Fairchild/ON Semiconductor MOSFET P-CH 200V 3.7A IPAK</p>	 <p>FQU5P20 FAIRCHILD FQU5P20 FAIRCHILD</p>	 <p>FQU6N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 4.4A IPAK</p>	 <p>FQU5N60CTU Fairchild/ON Semiconductor MOSFET N-CH 600V 2.8A IPAK</p>
 <p>FQU6N25TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 4.4A IPAK</p>	 <p>FQU5N60CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.8A IPAK</p>	 <p>FQU5P10 F FQU5P10 F</p>	 <p>FQU6N40C VB FQU6N40C VB</p>

heiße Teile

Mehr

 FQU2N60C	 FQU2N60CTU	 FQU2N60CTU	 D FQU2N65C	 FQU2N90TU
 FQU2N90TU	 FQU30N06L	 D FQU3N40TU	 FQU3N40TU	 FQU3N50C
 FQU3N50CTU	 FQU3N50CTU	 FQU3N60C	 FQU3N60CTU	 FQU3N60CTU
 D FQU3N60TU	 FQU3N60TU	 FQU4N20LTU	 FQU4N20TU	 FQU4N20TU
 FQU4N25TU	 FQU4N25TU	 FQU4N50TU	 FQU4N50TU	 FQU4N50TU_WS
 FQU4N60C	 FQU4P25TU	 D FQU4P25TU	 FQU5N40TU	 FQU5N40TU
 FQU5N50C	 D FQU5N50CS	 FQU5N50CTU	 FQU5N50CTU	 FQU5N60C
 FQU5N60CTU	 FQU5N60CTU	 FQU5N65C	 FQU5P20TU	 FQU6N40C
 FQU6N60C	 FQU6N65C	 FQU7N10L	 D FQU7N10TU	 FQU7N20TU
 FQU7N20TU	 FQU7N60C	 FQU7N65C	 FQU8P10TU	 FQU8P10TU

Contact us: Info@Y-IC.com

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